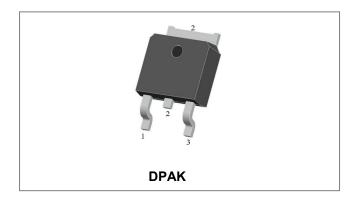






STD20100CE SCHOTTKY RECTIFIER



Features

- 150°C T_J operation
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Trench MOS Schottky technology
- Terminals finish: 100% Pure Tin
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- · Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	V _{RRM} V _{RWM}	-	100	V
DC Blocking Voltage	VRWM VR		100	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=105°C, rectangular wave form	10(Per Leg) 20(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	150	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop (Per Leg) *	V _{F1}	@ 5A, Pulse, T _J = 25 °C @ 10A, Pulse, T _J = 25 °C	0.57 0.72	- 0.80	V
	V _{F2}	@ 5A, Pulse, T _J = 125 °C @ 10A, Pulse, T _J = 125 °C	0.54 0.66	- 0.70	V
Reverse Current (Per Leg) *	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}\text{C}$	5	300	uA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}\text{C}$	3	12	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25 ^{\circ}C$ $f_{SIG} = 1MHz$	280	-	pF

Pulse width < 300 µs, duty cycle < 2%

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •



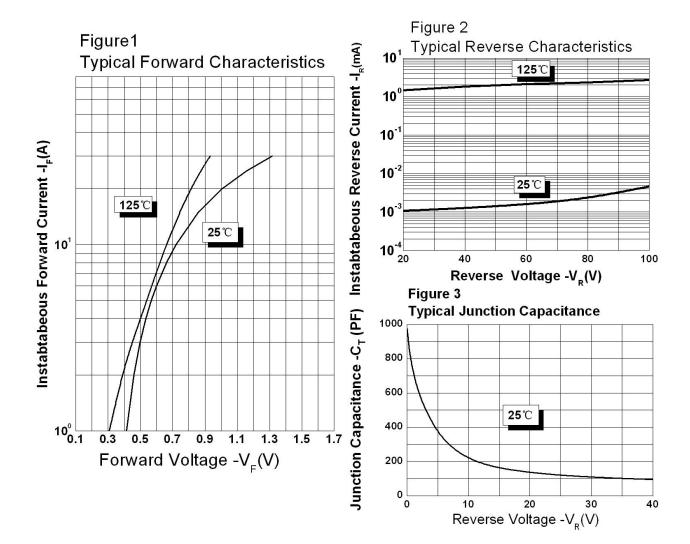




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	$R_{ heta JC}$	DC operation	2	°C/W
Approximate Weight	wt	-	0.39	g
Case Style	DPAK			

Ratings and Characteristics Curves



[•] China - Germany - Korea - Singapore - United States •

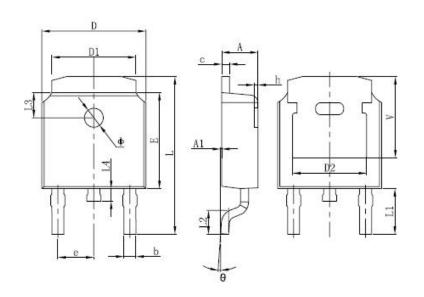
http://www.smc-diodes.com - sales@ smc-diodes.com •







Mechanical Dimensions DPAK



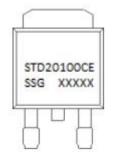
SYMBOL	Dimensions in millimeters			
STWIBOL	Min.	Тур.	Max.	
Α	2.18	-	2.39	
A1	-	-	0.13	
b	0.64	-	0.89	
С	0.46	-	0.89	
D	6.35	-	6.73	
D1	4.95	-	5.46	
D2	4.32	-	-	
E	5.97	6.1	6.22	
е	2.29BSC			
L	9.4 - 10.41			
L1	2.90 REF.			
L2	1.4	1.52	1.78	
L3	1.60 REF.			
L4	-	-	1.02	
Ф	1.1	-	1.3	
Θ	0°	-	10°	
V	5.21	_	-	

Ordering Information

Device	Package	Shipping
ST20100CE	DPAK	2500pcs / reel
ST20100CETR	DPAK	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

ST = Device Type
D = Package type
20 = Forward Current (20A)
100 = Reverse Voltage(100V)
CE = Configuration

 SSG
 = SSG

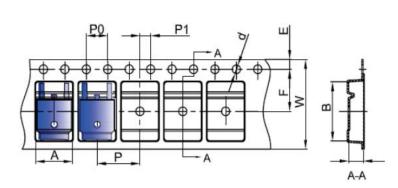
 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Carrier Tape Specification DPAK



SYMBOL	Millimeters			
STMBOL	Min.	Max.		
Α	6.80	7.00		
В	10.40	10.60		
С	2.60	2.80		
d	Ф1.45	Ф1.65		
E	1.65	1.85		
F	7.40	7.60		
P0	3.90	4.10		
Р	7.90	8.10		
P1	1.90	2.10		
W	15.90	16.30		

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •









DISCLAIMER:

- 1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC Diode Solutions sales department for the latest version of the datasheet(s).
- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
- 3- In no event shall SMC Diode Solutions be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC Diode Solution assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.
- 4- In no event shall SMC Diode Solutions be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.
- 5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC Diode Solutions.
- 6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC Diode Solutions.
- 7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..